NSN 5961-01-130-3829

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-130-3829 **Inclosure Material:** Metal **Overall Length:** 4.043 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-205ab **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 275.00 amperes collector current, dc and 5000.00 amperes collector current, dc preset **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0